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PATENT
Attorney Docket No.: 082666-000100US
Client Ref. No.: 0338-4033USD

Assistant Commissioner for Patents
Washington, D.C. 20231

On February 24, 2003

TOWNSEND and TOWNSEND and CREW LLP

By: Lata Olivier

Lata Olivier

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Jin-Kuo Ho, et al.

Application No.: 09/388,265

Filed: September 1, 1999

For: OHMIC CONTACT TO
SEMICONDUCTOR DEVICES AND
METHOD OF MANUFACTURING THE
SAME

Examiner: H. Vu

Art Unit: 2811

AMENDMENT

FAX RECEIVED

FEB 24 2003

TECHNOLOGY CENTER 2800

Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Applicants request a one-month extension of time from January 23, 2003 to February 23, 2003 and authorize the Commissioner to charge the fee therefor to our deposit account in accordance with the attached Fee Transmittal sheet.

In response to the Office Action mailed October 23, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

- 1 16. (Twice Amended) An ohmic contact in a semiconductor device,
2 which is formed on a p-type semiconductor material, the ohmic contact comprising a
3 layer of p-type semiconductor oxide and a conductive layer.